

# **isc** Silicon NPN Power Transistor

# BU212

### DESCRIPTION

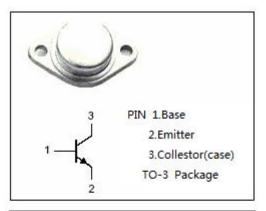
- High Collector-Base Breakdown Voltage-
  - : V<sub>(BR)CBO</sub>= 750V (Min)
- High Current Capability
- High Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

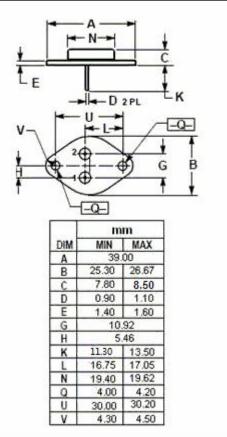
## APPLICATIONS

• Designed for TV horizontal output and high power switching applications.

#### ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25°C)

SYMBOL	PARAMETER	МАХ	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	750	V
V <sub>CEO</sub>	Collector-Emitter Voltage	350	V
V <sub>EBO</sub>	Emitter-Base Voltage	8	V
lc	Collector Current-Continuous	12	А
I <sub>СМ</sub>	Collector Current-Peak	15	А
Pc	Collector Power Dissipation @T <sub>c</sub> =25℃	85	W
Tj	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature Range	-65~150	°C







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## **ELECTRICAL CHARACTERISTICS**

#### T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V(BR)CEO	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 50mA; I <sub>B</sub> = 0	350			V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = 1mA; I <sub>E</sub> = 0	750			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 1mA; I <sub>C</sub> = 0	8			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 8A; I <sub>B</sub> = 2.5A			2.0	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = 8A; I <sub>B</sub> = 2.5A			2.2	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = 750V; I <sub>E</sub> = 0			0.1	mA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 8V; I <sub>C</sub> = 0			0.1	mA
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 8A; V <sub>CE</sub> = 5V	5			
fT	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.5A; V <sub>CE</sub> = 10V		6		MHz
t <sub>f</sub>	Fall Time	I <sub>C</sub> = 8A; I <sub>B1</sub> = -I <sub>B2</sub> = 2.5A			1.0	μ <b>S</b>

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